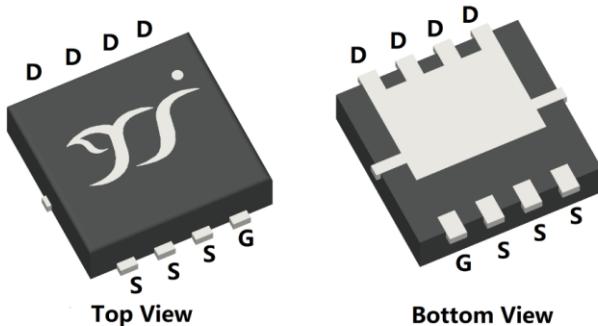
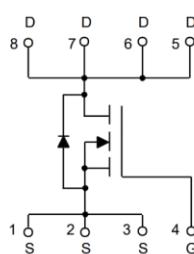


## N-Channel Enhancement Mode Field Effect Transistor



**PDFN3333-8L**



### Product Summary

- $V_{DS}$  60V
- $I_D$  60A
- $R_{DS(ON)}$  (at  $V_{GS}=10V$ )  $<7.5m\Omega$
- $R_{DS(ON)}$  (at  $V_{GS}=4.5V$ )  $<12.4m\Omega$
- 100% EAS Tested
- 100%  $\nabla V_{DS}$  Tested

### General Description

- Excellent package for heat dissipation
- High density cell design for low  $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

### Applications

- DC-DC Converters
- Power management functions
- Industrial and Motor Drive application

### ■ Limiting Values

| Parameter                              | Conditions   |                               | Symbol   | Min | Max  | Unit |
|--|--|-------------------------------|----------|-----|------|------|
| Drain-source Voltage                   | $T_A=25^\circ C, V_{GS}=10V$                                 | $T_A=100^\circ C, V_{GS}=10V$ | $V_{DS}$ | -   | 60   | V    |
| Gate-source Voltage                    |  |                               | $V_{GS}$ | -20 | 20   |      |
| Continuous Drain Current (Note 1,2)    | Steady-State   | $T_A=25^\circ C, V_{GS}=10V$  | $I_D$    | -   | 11.9 | A    |
| Continuous Drain Current (Note 1,3)    |  | $T_A=100^\circ C, V_{GS}=10V$ |          | -   | 7.5  |      |
| Pulsed Drain Current                   | $T_C=25^\circ C, t_p \leq 10\mu s$                           |                               | $I_{DM}$ | -   | 240  |      |
| Maximum Body-Diode Continuous Current  | $T_C=25^\circ C$   |                               | $I_S$    |     | 45   |      |
| Avalanche Energy (non-repetitive )     | $T_J=25^\circ C, V_G=10V, R_G=25\Omega, L=0.5mH, I_{AS}=17A$ |                               | EAS      | -   | 72.2 | mJ   |
| Total Power Dissipation (Note 1,2)     | Steady-State   | $T_A=25^\circ C$              | $P_D$    | -   | 1.92 | W    |
| Total Power Dissipation (Note 1,3)     |  | $T_A=100^\circ C$             |          | -   | 0.76 |      |
| Junction and Storage Temperature Range | $T_J, T_{STG}$   |                               |          | -55 | 150  | °C   |

### ■ Thermal Resistance

| Parameter                                       | Symbol          | Typ | Max | Units |
|---|-----------------|-----|-----|-------|
| Thermal Resistance Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | -   | 65  | °C/W  |
| Thermal Resistance Junction-to-Case             | $R_{\theta JC}$ | -   | 2.5 |       |

### ■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| YJQ7D5G06AJ   | F1           | 7D5G06A | 5000                 | 10000                   | 100000                     | 13" reel      |



# YJQ7D5G06AJ

## ■ Electrical Characteristics

| Parameter                         | Symbol       | Conditions   | Min | Typ  | Max       | Units   |
|-----------------------------------|--------------|--|-----|------|-----------|---------|
| <b>Static Parameter</b>           |              |  |     |      |           |         |
| Drain-Source Breakdown Voltage    | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A, T_j=25^\circ C$                            | 60  | -    | -         | V       |
| Zero Gate Voltage Drain Current   | $I_{DSS}$    | $V_{DS}=60V, V_{GS}=0V, T_j=25^\circ C$                              | -   | -    | 1         | $\mu A$ |
|                                   |              | $V_{DS}=60V, V_{GS}=0V, T_j=150^\circ C$                             | -   | -    | 100       |         |
| Gate-Source Leakage Current       | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V, T_j=25^\circ C$                          | -   | -    | $\pm 100$ | nA      |
| Gate Threshold Voltage            | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A, T_j=25^\circ C$                        | 1.4 | 1.9  | 2.4       | V       |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=25A, T_j=25^\circ C$                                | -   | 6    | 7.5       | mΩ      |
|                                   |              | $V_{GS}=4.5V, I_D=18A, T_j=25^\circ C$                               | -   | 8.3  | 12.4      | mΩ      |
| Diode Forward Voltage             | $V_{SD}$     | $I_S=25A, V_{GS}=0V, T_j=25^\circ C$                                 | -   | 0.86 | 1.2       | V       |
| Gate Resistance                   | $R_G$        | $f=1MHz, T_j=25^\circ C$   | -   | 2    | -         | Ω       |
| <b>Dynamic Parameters</b>         |              |  |     |      |           |         |
| Input Capacitance                 | $C_{iss}$    | $V_{DS}=30V, V_{GS}=0V, f=1MHz, T_j=25^\circ C$                      | -   | 1270 | -         | pF      |
| Output Capacitance                | $C_{oss}$    |  | -   | 300  | -         |         |
| Reverse Transfer Capacitance      | $C_{rss}$    |  | -   | 9    | -         |         |
| <b>Switching Parameters</b>       |              |  |     |      |           |         |
| Total Gate Charge                 | $Q_g$        | $V_{GS}=10V, V_{DS}=30V, I_D=25A, T_j=25^\circ C$                    | -   | 21.5 | -         | nC      |
| Gate-Source Charge                | $Q_{gs}$     |  | -   | 4.3  | -         |         |
| Gate-Drain Charge                 | $Q_{gd}$     |  | -   | 4.1  | -         |         |
| Reverse Recovery Charge           | $Q_{rr}$     | $I_F=25A, di/dt=100A/\mu s, V_{GS}=0V, V_R=30V, T_j=25^\circ C$      | -   | 11   | -         | nC      |
| Reverse Recovery Time             | $t_{rr}$     |  | -   | 21   | -         | ns      |
| Turn-on Delay Time                | $t_{D(on)}$  | $V_{GS}=10V, V_{DS}=30V, I_D=25A, R_{GEN}=2.7\Omega, T_j=25^\circ C$ | -   | 10.3 | -         | ns      |
| Turn-on Rise Time                 | $t_r$        |  | -   | 52.2 | -         |         |
| Turn-off Delay Time               | $t_{D(off)}$ |  | -   | 24.4 | -         |         |
| Turn-off Fall Time                | $t_f$        |  | -   | 6.1  | -         |         |

Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of  $R_{\theta JA}$  is measured with the device mounted on the 40mm\*40mm\*1.1mm single layer FR-4 PCB board with 1 in<sup>2</sup> pad of 2oz. Copper, in the still air environment with  $T_A=25^\circ C$ . The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- Thermal resistance from junction to soldering point (on the exposed drain pad).

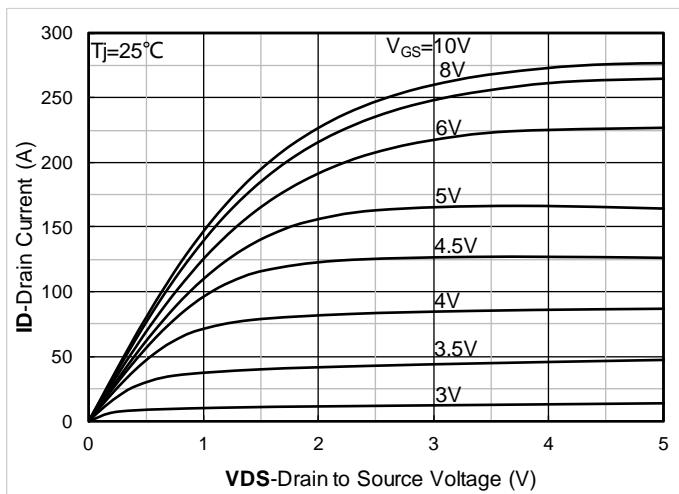
**■Typical Electrical and Thermal Characteristics Diagrams**

Figure 1. Output Characteristics; typical values

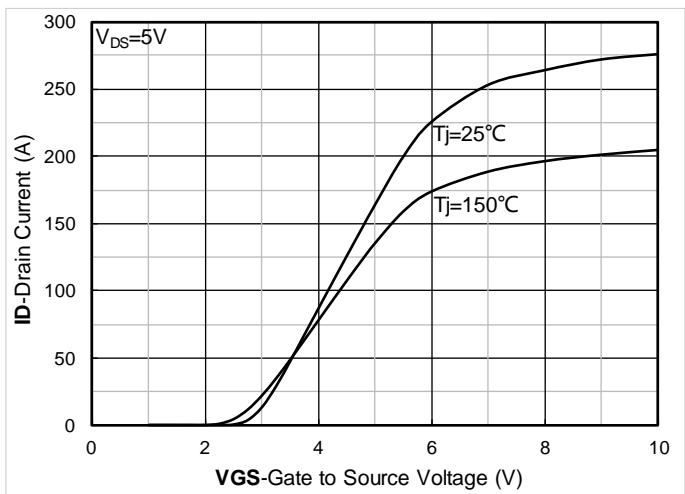


Figure 2. Transfer Characteristics; typical values

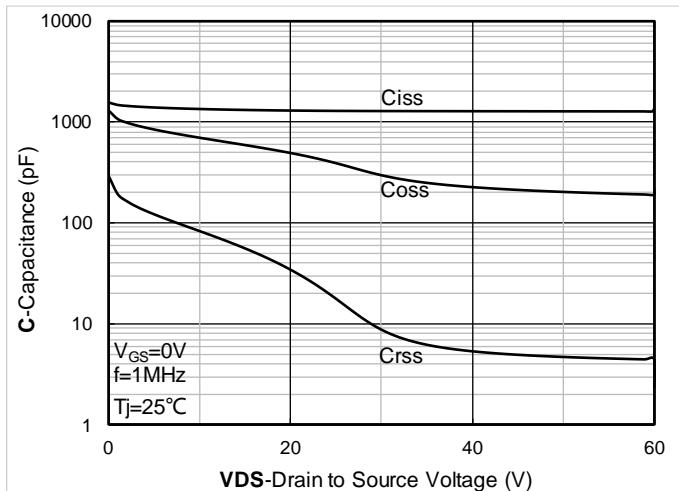


Figure 3. Capacitance Characteristics; typical values

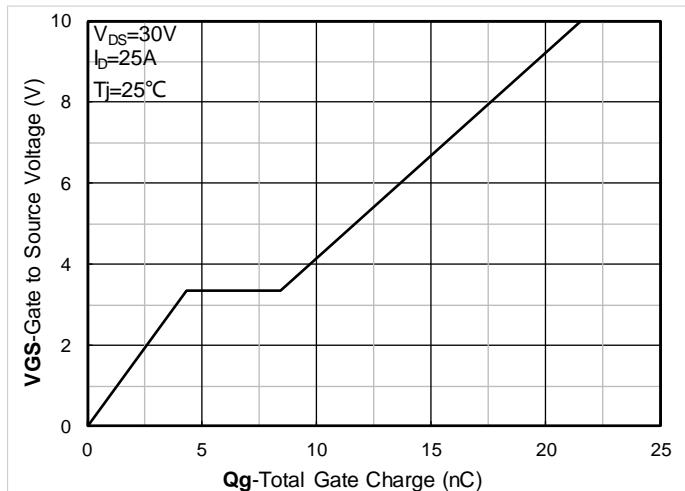


Figure 4. Gate Charge; typical values

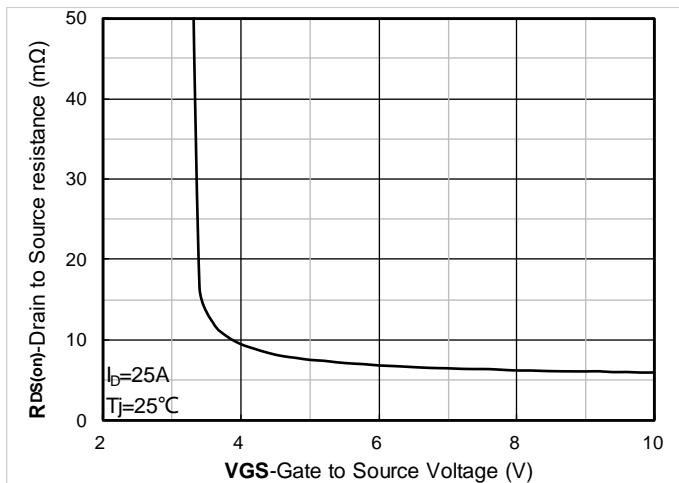


Figure 5. On-Resistance vs. Gate to Source Voltage; typical values

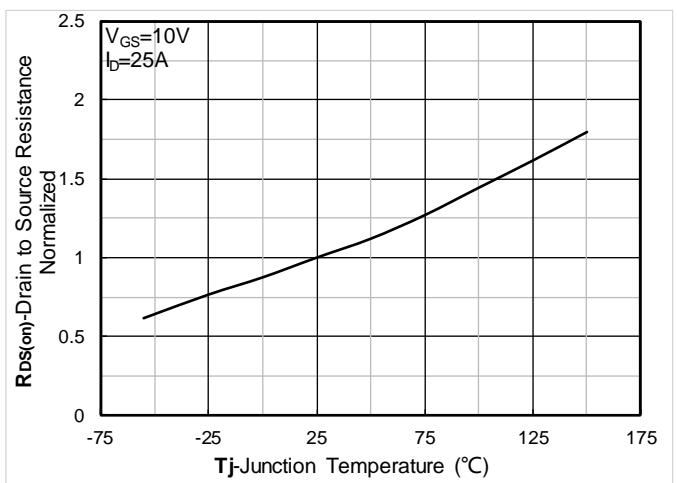


Figure 6. Normalized On-Resistance

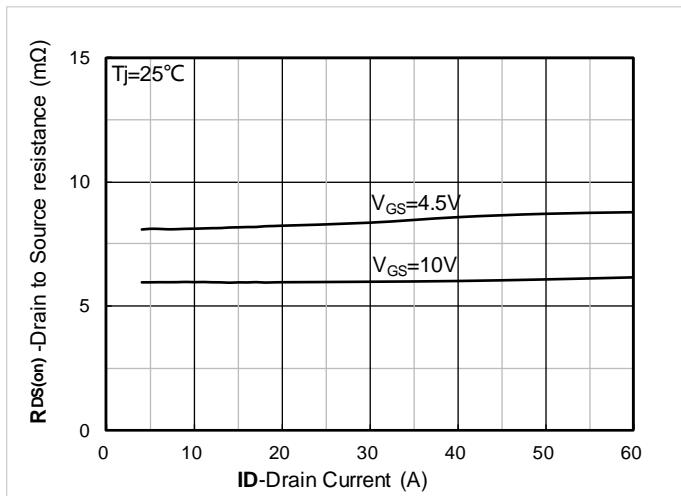


Figure 7.  $R_{DS(on)}$  vs. Drain Current; typical values

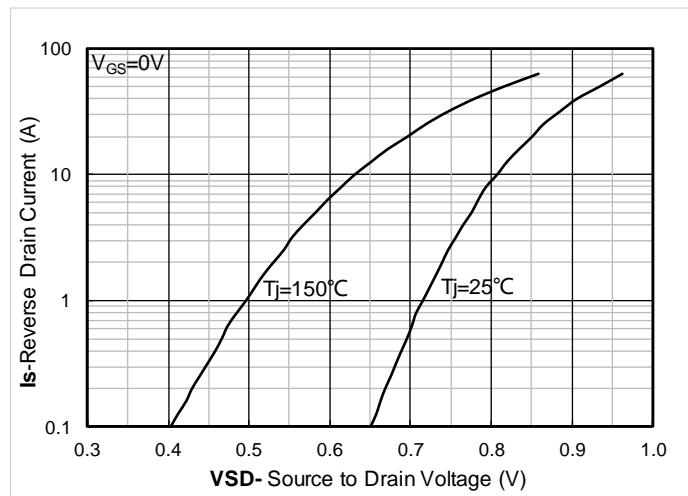


Figure 8. Forward characteristics of reverse diode; typical values

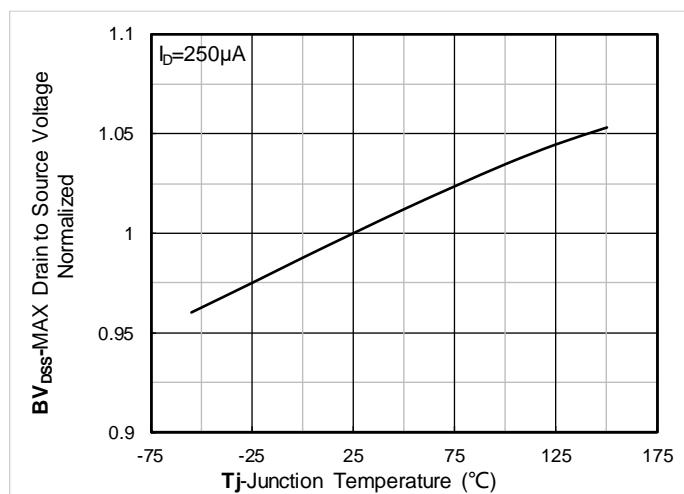


Figure 9. Normalized breakdown voltage

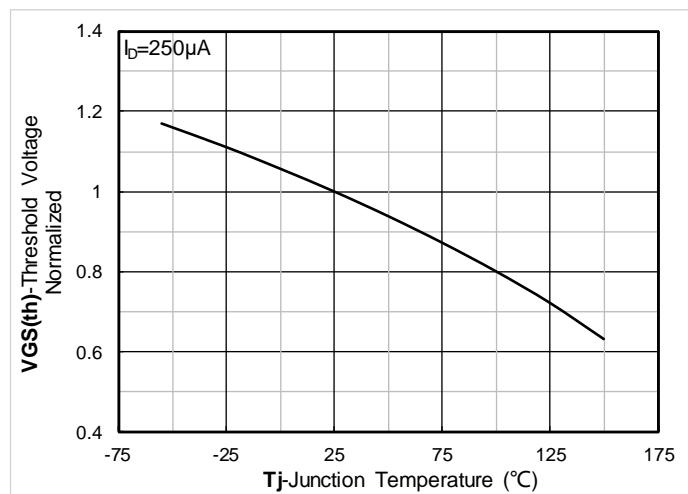


Figure 10. Normalized Threshold voltage

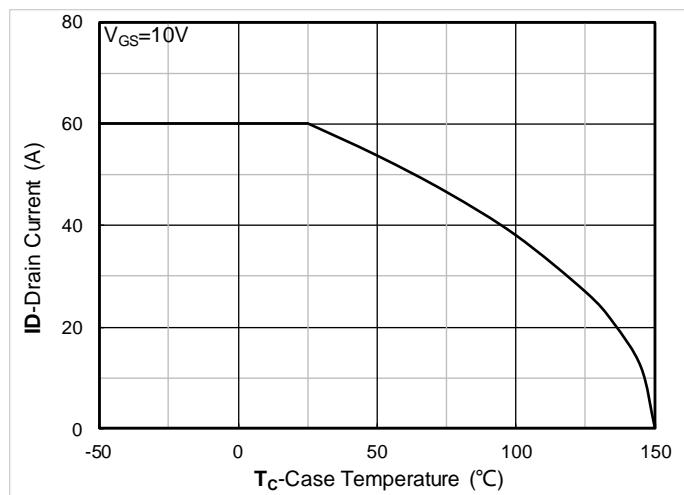


Figure 11. Current dissipation

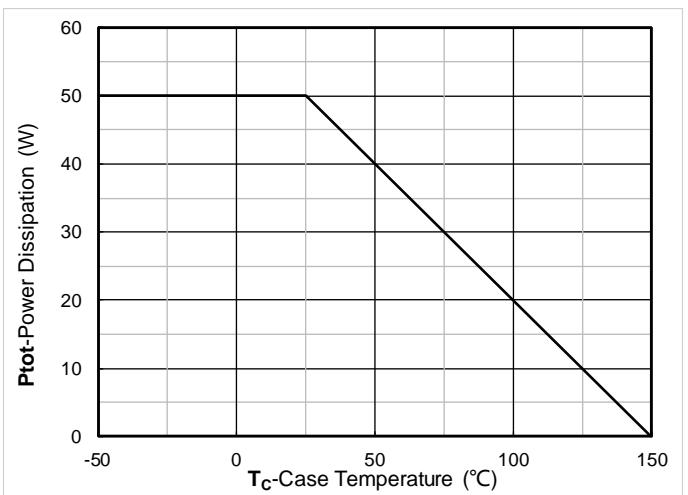


Figure 12. Power dissipation

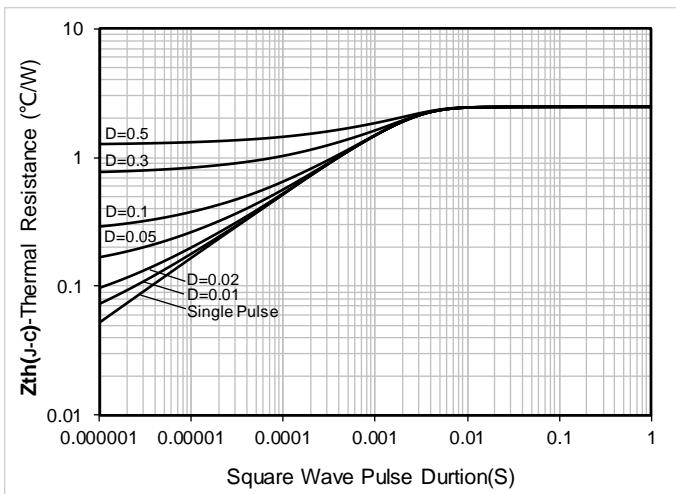


Figure 13. Maximum Transient Thermal Impedance

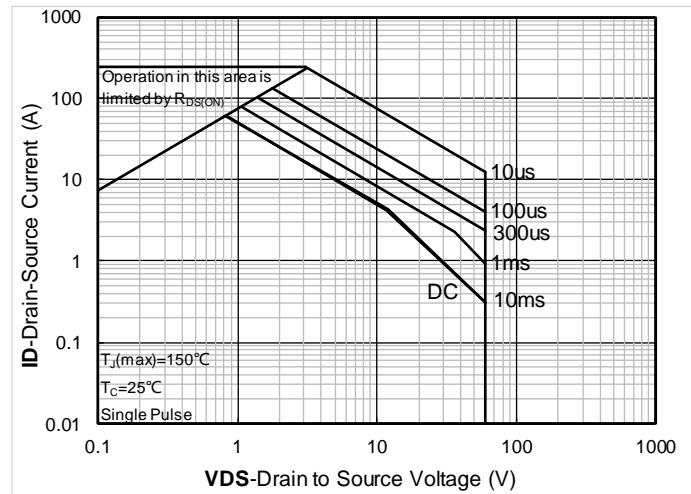


Figure 14. Safe Operation Area

## ■ Test Circuits & Waveforms

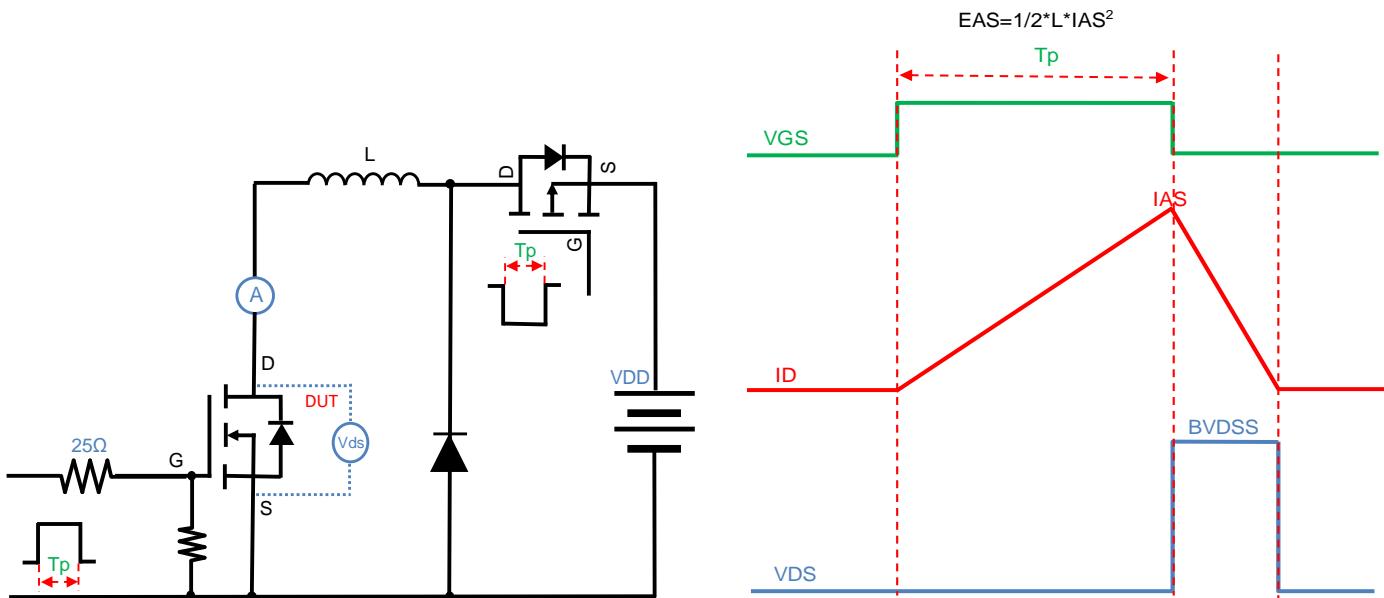


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

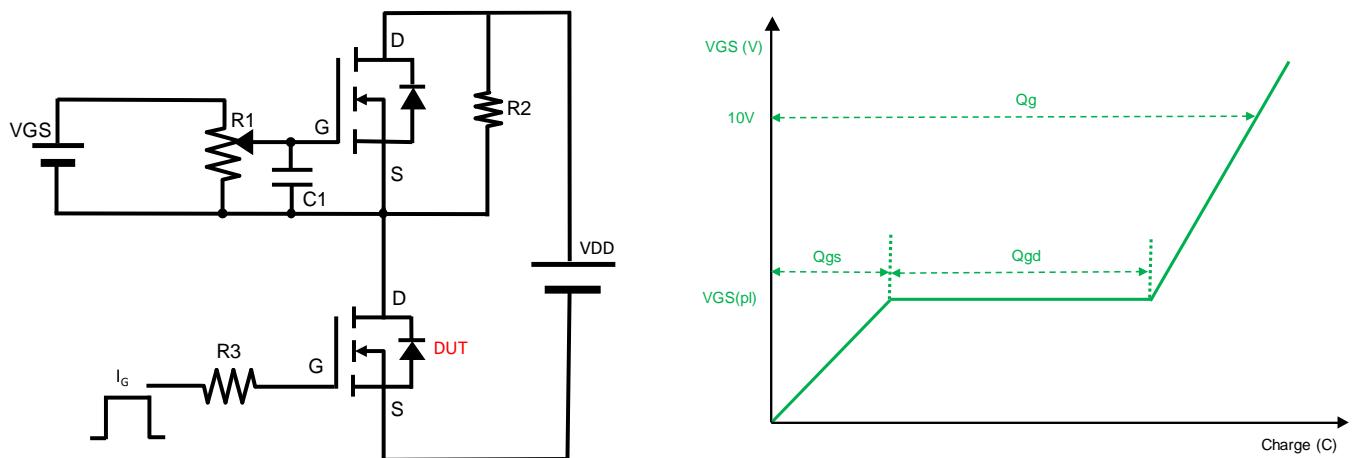


Figure B. Gate Charge Test Circuit & Waveform

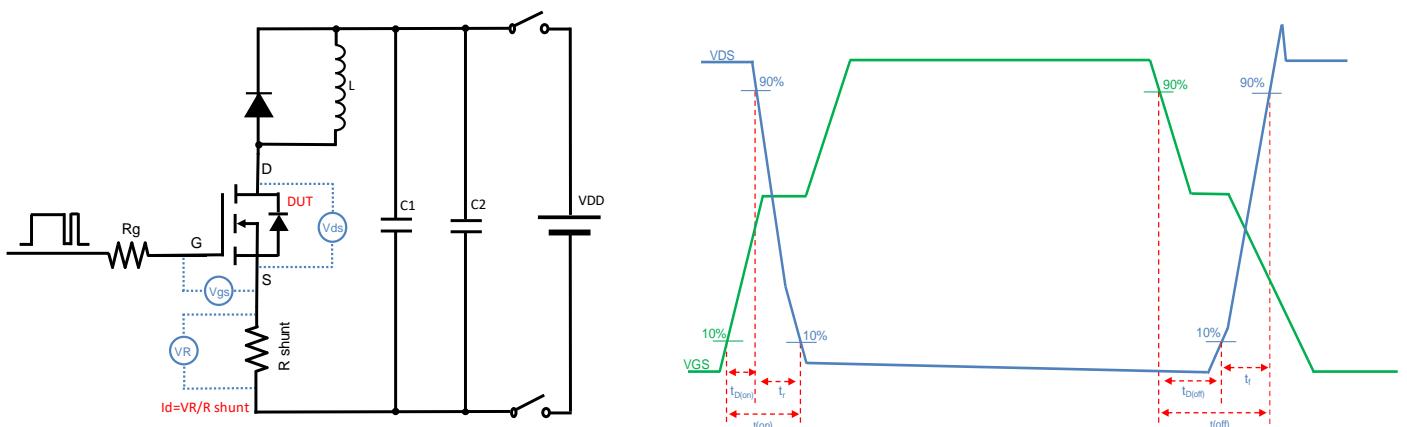


Figure C. Resistive Switching Test Circuit & Waveform

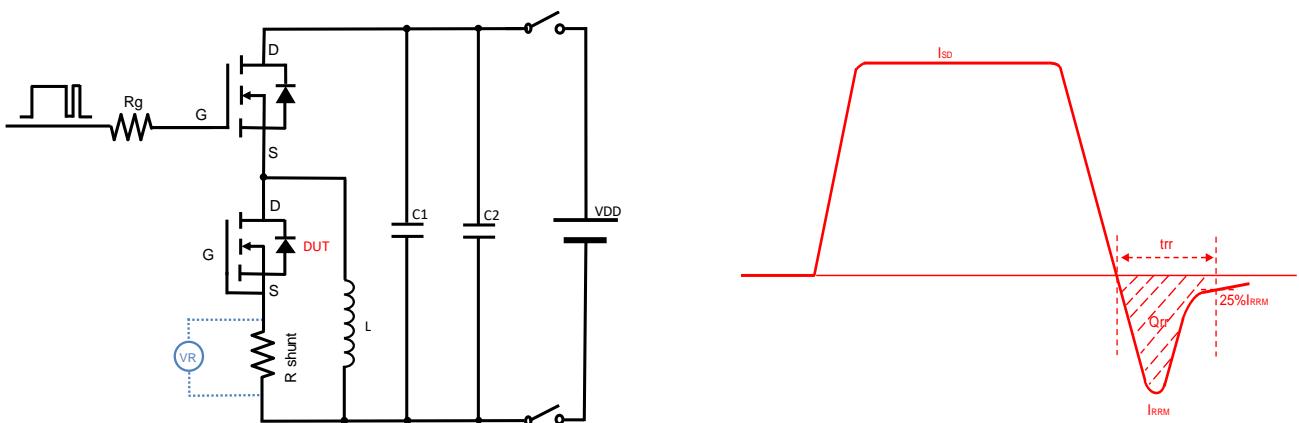
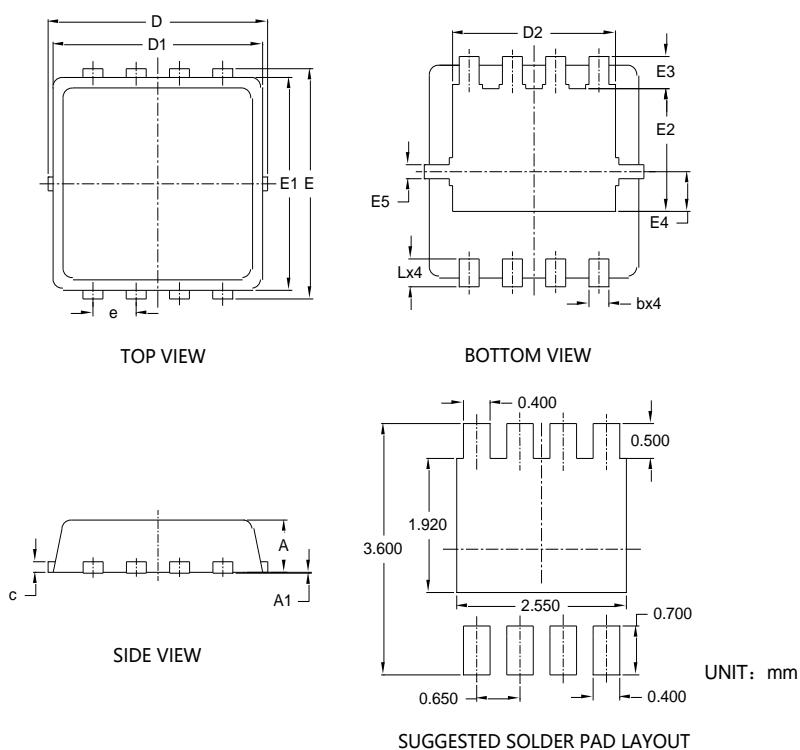


Figure D. Diode Recovery Test Circuit & Waveform



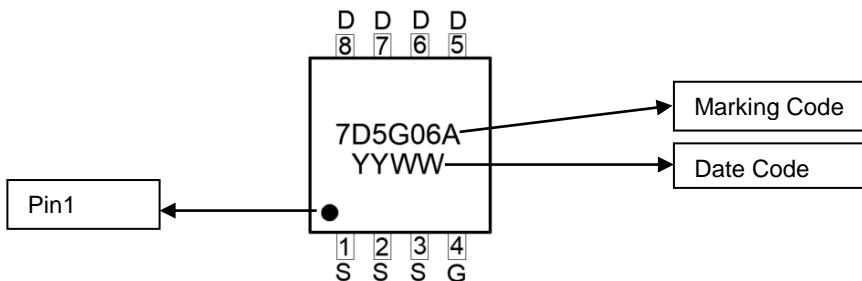
## ■ PDFN3333-8L-A-0.75mm Package information



| SYMBOL | DIMENSIONS |       |            |       |
|--------|------------|-------|------------|-------|
|        | INCHES     |       | Millimeter |       |
|        | MIN.       | MAX.  | MIN.       | MAX.  |
| A      | 0.028      | 0.033 | 0.700      | 0.850 |
| A1     | 0.000      | 0.002 | 0.000      | 0.050 |
| b      | 0.008      | 0.016 | 0.200      | 0.400 |
| c      | 0.004      | 0.010 | 0.100      | 0.250 |
| D      | 0.124      | 0.136 | 3.150      | 3.450 |
| D1     | 0.118      | 0.130 | 3.000      | 3.300 |
| D2     | 0.089      | 0.104 | 2.250      | 2.650 |
| E      | 0.124      | 0.136 | 3.150      | 3.450 |
| E1     | 0.114      | 0.126 | 2.900      | 3.200 |
| E2     | 0.061      | 0.076 | 1.540      | 1.940 |
| E3     | 0.011      | 0.026 | 0.280      | 0.650 |
| E4     | 0.022 REF  |       | 0.570 REF  |       |
| E5     | 0.008 REF  |       | 0.200 REF  |       |
| e      | 0.026 BSC  |       | 0.650 BSC  |       |
| L      | 0.012      | 0.020 | 0.300      | 0.500 |

## NOTE:

- 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
- 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
- 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

**■ Marking Information****Note:**

1. All marking is at middle of the product body
2. All marking is in laser printing
3. 7D5G06A is marking code, YYWW is date code, "YY" is year, "WW" is week
4. Body color: Black



## Disclaimer

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